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INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Application Number	10/653,152
(Use as many sheets as necessary)				Filing Date	September 3, 2003
Sheet	1	of	1	First Named Inventor	Chandra Mouli
				Art Unit	NHAP 2815
				Examiner Name	Not Yet Assigned <i>R. Wilson</i>
				Attorney Docket Number	M4065.0970/P970

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
<i>Chandra Mouli</i>					

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Foreign Patent Document Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
<i>Chandra Mouli</i>	GA	Chapter 1, "Ionizing radiation effects on MOS devices and -es", pages 35-62.			
<i>Chandra Mouli</i>	GB	B.C. BURKEY et al., "The Pinned Photodiode for an Interline-Transfer CCD Image Sensor", CH2099-0/84/0000-0028, 1984.			
<i>Chandra Mouli</i>	CC	MASAHIRO USHIYAMA et al., "Suppression of Anomalous Leakage Current in Tunnel Oxides by Fluorine Implantation to Realize Highly Reliable Flash Memory," 1999 Symposium on VLSI Technology Digest of Technical Papers			
<i>Chandra Mouli</i>	OD	KIYONORI OHYU et al., "Improvement of SiO ₂ /Si Interface Properties Utilising Fluorine Ion Implantation and Drive-in Diffusion," Japanese Journal of Applied Physics, Vol. 28, No. 6, June, 1989, pp. 1041-1045.			

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R. Wilson 12/8/04